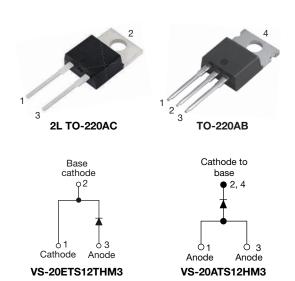
VS-20ETS12THM3, VS-20ATS12HM3

Vishay Semiconductors

High Voltage, Input Rectifier Diode, 20 A

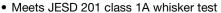


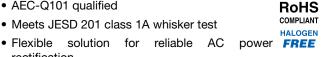
PRIMARY CHARACTERISTICS					
I _{F(AV)} 20 A					
V_{R}	1200 V				
V _F at I _F	1.1 V				
I _{FSM}	300 A				
T _J max.	150 °C				
Package	2L TO-220AC, 3L TO-220AB				
Circuit configuration	Single, common anode				

FEATURES

rectification

- Glass passivated pellet chip junction
- AEC-Q101 qualified





- High surge, low V_F rugged blocking diode for DC charging stations
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- On-board and off-board EV/HEV battery chargers
- Input rectification

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS								
Capacitive input filter T _A = 55 °C, T _J = 125 °C common heatsink of 1 °C/W	16.3	21	А					

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Sinusoidal waveform	20	Α				
V _{RRM}		1200	V				
I _{FSM}		300	Α				
V _F	10 A, T _J = 25 °C	1.0	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-20ETS12THM3, VS-20ATS12HM3	1200	1300	1				

VS-20ETS12THM3, VS-20ATS12HM3

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	T _C = 105 °C, 180° conduction half sine wave	20				
Maximum peak one cycle	1	10 ms sine pulse, rated V _{RRM} applied	250	Α			
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	300				
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s			
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	442	A-5			
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s			

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL TEST CONDITIONS VALUES U					
Maximum forward voltage drop	V_{FM}	20 A, T _J = 25 °C	1.1	V		
Forward slope resistance	r _t	T 450 %C		10.4	mΩ	
Threshold voltage	V _{F(TO)}	1J=150 C	T _J = 150 °C			
Maximum reverse leakage current	le	$T_J = 25 ^{\circ}\text{C}$ $V_B = \text{Rated } V_{BBB}$		0.1	mA	
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	VR = nated VRRM	1.0	IIIA	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and sto temperature range	rage	T_J, T_{Stg}		-40 to +150	°C		
Maximum thermal resistance, junction to case		R_{thJC}	DC operation 1.		- °C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased 0.5				
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque maximum				12 (10)	(lbf ⋅ in)		
Marking device			Case style 2L TO-220AC	20ETS	S12TH		
			Case style 3L TO-220AB	20ATS12H			

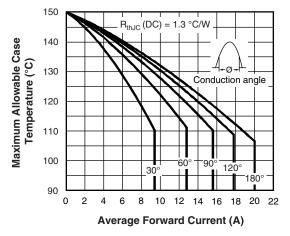


Fig. 1 - Current Rating Characteristics

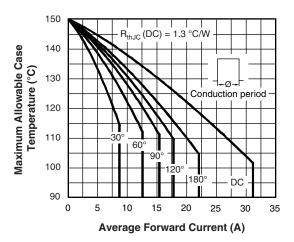


Fig. 2 - Current Rating Characteristics

300



Vishay Semiconductors

At any rated load condition and with

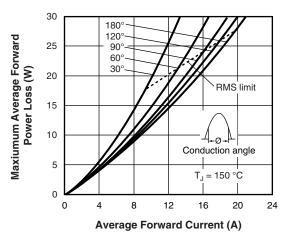
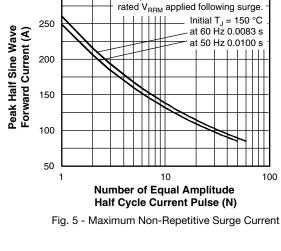


Fig. 3 - Forward Power Loss Characteristics



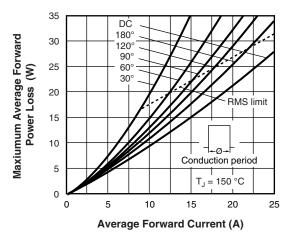


Fig. 4 - Forward Power Loss Characteristics

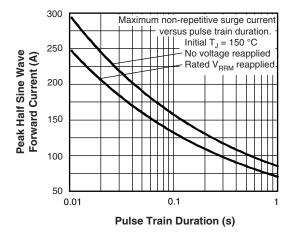


Fig. 6 - Maximum Non-Repetitive Surge Current

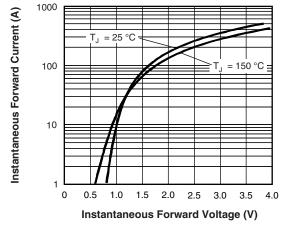


Fig. 7 - Forward Voltage Drop Characteristics

Vishay Semiconductors

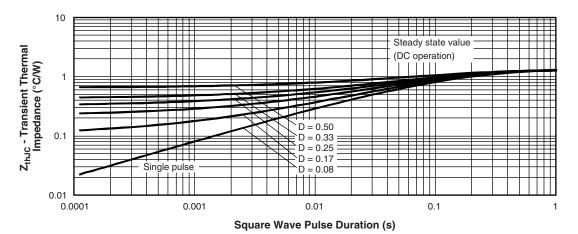
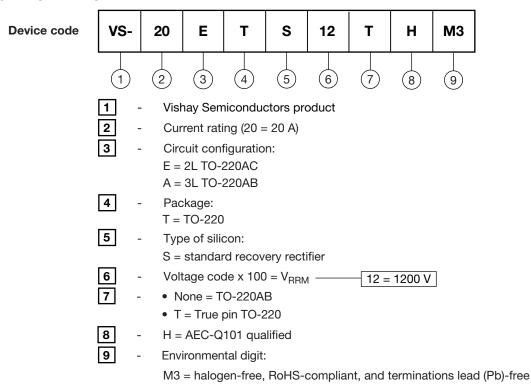


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-20ETS12THM3	50	1000	Antistatic plastic tubes			
VS-20ATS12HM3	50	1000	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS					
Dimensions	2L TO-220AC	www.vishay.com/doc?96069			
Dimensions	3L TO-220AB	www.vishay.com/doc?95222			
Part marking information	2L TO-220AC	www.vishay.com/doc?95391			
Part marking information	3L TO-220AB	www.vishay.com/doc?95028			



VS-20ETS12THM3, VS-20ATS12HM3

www.vishay.com

Vishay Semiconductors

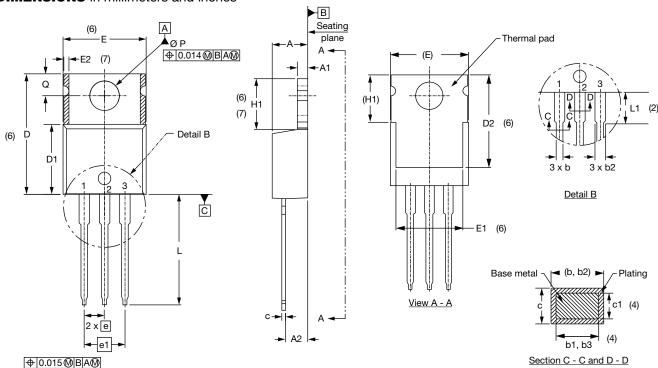
SPICE model	www.vishav.com/doc?96046
	•

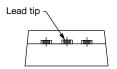


Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183		D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055		E	10.11	10.51	0.398	0.414	3, 6
A2	2.56	2.92	0.101	0.115		E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040		E2	-	0.76	-	0.030	7
b1	0.38	0.97	0.015	0.038	4	е	2.41	2.67	0.095	0.105	
b2	1.20	1.73	0.047	0.068		e1	4.88	5.28	0.192	0.208	
b3	1.14	1.73	0.045	0.068	4	H1	5.84	6.86	0.230	0.270	6, 7
С	0.36	0.61	0.014	0.024		L	13.52	14.02	0.532	0.552	
c1	0.36	0.56	0.014	0.022	4	L1	3.32	3.82	0.131	0.150	2
D	14.85	15.25	0.585	0.600	3	ØΡ	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

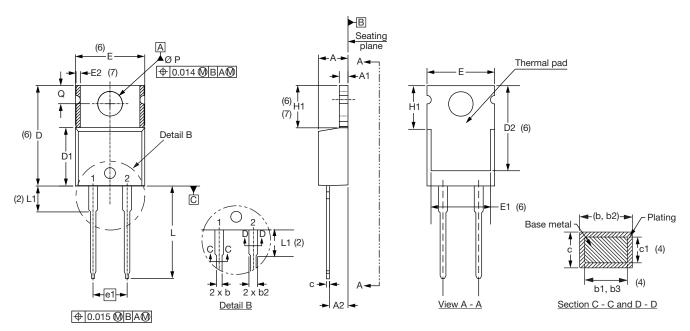
Revision: 06-Mar-2020 1 Document Number: 95222



Vishay Semiconductors

2L TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	NOTES	
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	ı	0.76	-	0.030	7
e1	4.88	5.28	0.192	0.208	
H1	5.84	6.86	0.230	0.270	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Ø	2.60	3.00	0.102	0.118	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except D2, where JEDEC® minimum is 0.480"

Legal Disclaimer Notice



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2019 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED